## REVISION HISTORY

| Revision | Description | Issue Date |
|---|---|---|
| Rev. 0.1 | Preliminary | Dec.06.2006 |
| Rev. 0.2 | Revised **TEST CONDITION** of $I_{SB1}$/$I_{DR}$<br>Revised $V_{TERM}$ to $V_{T1}$ and $V_{T2}$<br>Revised **FEATURES** & **ORDERING INFORMATION**<br>**Lead free and green package available** to **Green package available**<br>Added packing type in **ORDERING INFORMATION**<br>Deleted $T_{SOLDER}$ in **ABSOLUTE MAXIMUN RATINGS**<br>Revised **PACKAGE OUTLINE DIMENSION** | Aug.26.2009 |
| Rev. 0.3 | Revised **ORDERING INFORMATION** in page 9 | Aug.30.2010 |
| Rev. 1.0 | Revised Notes item 1 and 2 in page 3<br>1. $V_{IH}$(max) = $V_{CC}$ + 2.0V for pulse width less than 6ns.<br>2. $V_{IL}$(min) = $V_{SS}$ - 2.0V for pulse width less than 6ns.<br>Revised **ORDERING INFORMATION** | Aug.29.2013 |
| Rev. 1.1 | Deleted **WRITE CYCLE** Notes :<br>1. WE#,CE# must be high during all address transitions. in page 6 | Mar.22.2017 |

Lyontek Inc.

# LY612568

Rev. 1.1

## 5V 256K X 8 BIT HIGH SPEED CMOS SRAM

## FEATURES

- Fast access time : 15/20/25ns
- Low power consumption:
  Operating current: 100/80/75mA (TYP.)
  Standby current: 100μA (TYP.)
- Single 5V power supply
- All inputs and outputs TTL compatible
- Fully static operation
- Tri-state output
- Data retention voltage : 2.0V (MIN.)
- **Green package available**
- Package : 44-pin 400mil TSOP II

## GENERAL DESCRIPTION

The LY612568 is a 2,097,152-bit low power CMOS static random access memory organized as 262,144 words by 8 bits. It is fabricated using very high performance, high reliability CMOS technology. Its standby current is stable within the range of operating temperature.

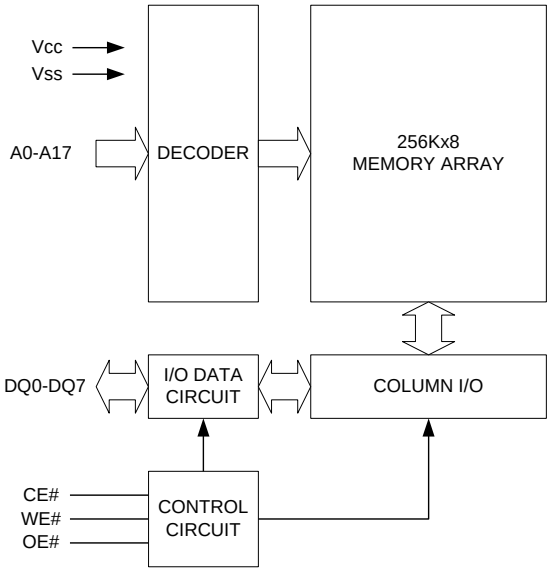
The LY612568 is well designed for low power application, and particularly well suited for battery back-up nonvolatile memory application.

The LY612568 operates from a single power supply of 5V and all inputs and outputs are fully TTL compatible.

## PRODUCT FAMILY

| Product Family | Operating Temperature | $V_{CC}$ Range | Speed | Power Dissipation | |
|---|---|---|---|---|---|
| | | | | Standby($I_{SB1}$,TYP.) | Operating($I_{CC}$,TYP.) |
| LY612568 | 0 ~ 70℃ | 4.5 ~ 5.5V | 15/20/25ns | 100μA | 100/80/75mA |
| LY612568(E) | -20 ~ 80℃ | 4.5 ~ 5.5V | 15/20/25ns | 100μA | 100/80/75mA |
| LY612568(I) | -40 ~ 85℃ | 4.5 ~ 5.5V | 15/20/25ns | 100μA | 100/80/75mA |

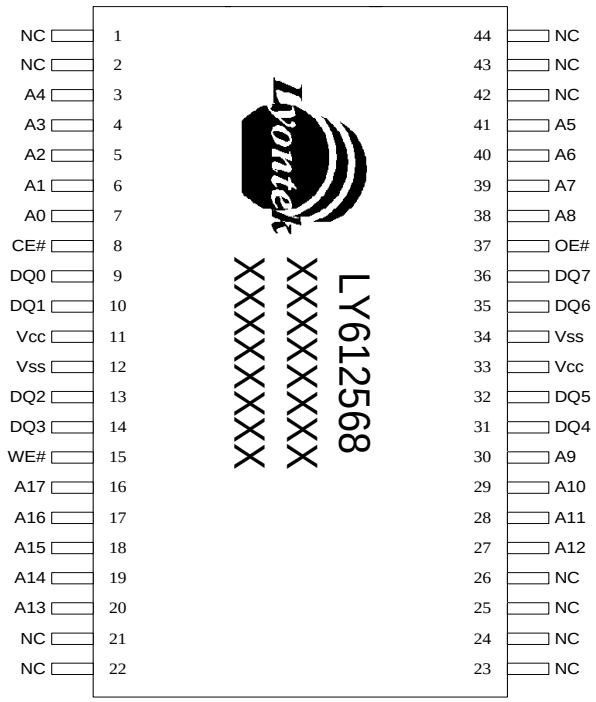
## FUNCTIONAL BLOCK DIAGRAM




## PIN DESCRIPTION

| SYMBOL | DESCRIPTION |
|---|---|
| A0 - A17 | Address Inputs |
| DQ0 - DQ7 | Data Inputs/Outputs |
| CE# | Chip Enable Inputs |
| WE# | Write Enable Input |
| OE# | Output Enable Input |
| $V_{CC}$ | Power Supply |
| $V_{SS}$ | Ground |
| NC | No Connection |

## PIN CONFIGURATION




TSOP II

## ABSOLUTE MAXIMUN RATINGS*

| PARAMETER | SYMBOL | RATING | UNIT |
|---|---|---|---|
| Voltage on $V_{CC}$ relative to $V_{SS}$ | $V_{T1}$ | -0.5 to 6.5 | V |
| Voltage on any other pin relative to $V_{SS}$ | $V_{T2}$ | -0.5 to $V_{CC}$+0.5 | V |
| Operating Temperature | $T_A$ | 0 to 70(C grade) | ℃ |
| | | -20 to 80(E grade) | |
| | | -40 to 85(I grade) | |
| Storage Temperature | $T_{STG}$ | -65 to 150 | ℃ |
| Power Dissipation | $P_D$ | 1 | W |
| DC Output Current | $I_{OUT}$ | 50 | mA |

*Stresses greater than those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to the absolute maximum rating conditions for extended period may affect device reliability.

## TRUTH TABLE

| MODE | CE# | OE# | WE# | I/O OPERATION | SUPPLY CURRENT |
|---|---|---|---|---|---|
| Standby | H | X | X | High-Z | $I_{SB1}$ |
| Output Disable | L | H | H | High-Z | $I_{CC}$ |
| Read | L | L | H | $D_{OUT}$ | $I_{CC}$ |
| Write | L | X | L | $D_{IN}$ | $I_{CC}$ |

Note: H = $V_{IH}$, L = $V_{IL}$, X = Don't care.

## DC ELECTRICAL CHARACTERISTICS

| PARAMETER | SYMBOL | TEST CONDITION | | MIN. | TYP. *4 | MAX. | UNIT |
|---|---|---|---|---|---|---|---|
| Supply Voltage | $V_{CC}$ | | | 4.5 | 5.0 | 5.5 | V |
| Input High Voltage | $V_{IH}$ *1 | | | 2.2 | - | $V_{CC}$+0.3 | V |
| Input Low Voltage | $V_{IL}$ *2 | | | - 0.3 | - | 0.8 | V |
| Input Leakage Current | $I_{LI}$ | $V_{CC} \geqq V_{IN} \geqq V_{SS}$ | | - 1 | - | 1 | µA |
| Output Leakage Current | $I_{LO}$ | $V_{CC} \geqq V_{OUT} \geqq V_{SS}$, Output Disabled | | - 1 | - | 1 | µA |
| Output High Voltage | $V_{OH}$ | $I_{OH}$ = -4mA | | 2.4 | - | - | V |
| Output Low Voltage | $V_{OL}$ | $I_{OL}$ = 8mA | | - | - | 0.4 | V |
| Average Operating Power supply Current | $I_{CC}$ | Cycle time = MIN. | -15 | - | 100 | 140 | mA |
| | | CE# = $V_{IL}$ , $I_{I/O}$ = 0mA | -20 | - | 80 | 110 | mA |
| | | Other pins at $V_{IH}$ or $V_{IL}$ | -25 | - | 75 | 100 | mA |
| Standby Power Supply Current | $I_{SB1}$ | CE#$\geqq$ $V_{CC}$ - 0.2V Other pins at 0.2V or $V_{CC}$-0.2V | | - | 0.1 | 3*5 | mA |

Notes:
1. $V_{IH}$(max) = $V_{CC}$ + 2.0V for pulse width less than 6ns.
2. $V_{IL}$(min) = $V_{SS}$ - 2.0V for pulse width less than 6ns.
3. Over/Undershoot specifications are characterized, not 100% tested.
4. Typical values are included for reference only and are not guaranteed or tested. Typical valued are measured at $V_{CC}$ = $V_{CC(TYP.)}$ and $T_A$ = 25℃
5. 1mA for special request

## CAPACITANCE ($T_A$ = 25℃, f = 1.0MHz)

| PARAMETER | SYMBOL | MIN. | MAX. | UNIT |
|---|---|---|---|---|
| Input Capacitance | $C_{IN}$ | - | 8 | pF |
| Input/Output Capacitance | $C_{I/O}$ | - | 10 | pF |

Note : These parameters are guaranteed by device characterization, but not production tested.

## AC TEST CONDITIONS

| | |
|---|---|
| Input Pulse Levels | 0.2V to $V_{CC}$ - 0.2V |
| Input Rise and Fall Times | 3ns |
| Input and Output Timing Reference Levels | 1.5V |
| Output Load | $C_L$ = 30pF + 1TTL, $I_{OH}/I_{OL}$ = -8mA/16mA |

## AC ELECTRICAL CHARACTERISTICS

### (1) READ CYCLE

| PARAMETER | SYM. | LY612568-15 | | LY612568-20 | | LY612568-25 | | UNIT |
|---|---|---|---|---|---|---|---|---|
| | | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | |
| Read Cycle Time | $t_{RC}$ | 15 | - | 20 | - | 25 | - | ns |
| Address Access Time | $t_{AA}$ | - | 15 | - | 20 | - | 25 | ns |
| Chip Enable Access Time | $t_{ACE}$ | - | 15 | - | 20 | - | 25 | ns |
| Output Enable Access Time | $t_{OE}$ | - | 7 | - | 8 | - | 9 | ns |
| Chip Enable to Output in Low-Z | $t_{CLZ}$* | 4 | - | 4 | - | 4 | - | ns |
| Output Enable to Output in Low-Z | $t_{OLZ}$* | 0 | - | 0 | - | 0 | - | ns |
| Chip Disable to Output in High-Z | $t_{CHZ}$* | - | 7 | - | 8 | - | 9 | ns |
| Output Disable to Output in High-Z | $t_{OHZ}$* | - | 7 | - | 8 | - | 9 | ns |
| Output Hold from Address Change | $t_{OH}$ | 3 | - | 3 | - | 3 | - | ns |

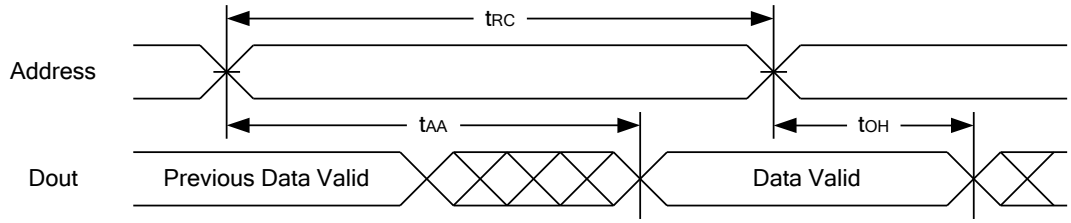
### (2) WRITE CYCLE

| PARAMETER | SYM. | LY612568-15 | | LY612568-20 | | LY612568-25 | | UNIT |
|---|---|---|---|---|---|---|---|---|
| | | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | |
| Write Cycle Time | $t_{WC}$ | 15 | - | 20 | - | 25 | - | ns |
| Address Valid to End of Write | $t_{AW}$ | 12 | - | 16 | - | 20 | - | ns |
| Chip Enable to End of Write | $t_{CW}$ | 12 | - | 16 | - | 20 | - | ns |
| Address Set-up Time | $t_{AS}$ | 0 | - | 0 | - | 0 | - | ns |
| Write Pulse Width | $t_{WP}$ | 10 | - | 11 | - | 12 | - | ns |
| Write Recovery Time | $t_{WR}$ | 0 | - | 0 | - | 0 | - | ns |
| Data to Write Time Overlap | $t_{DW}$ | 8 | - | 9 | - | 10 | - | ns |
| Data Hold from End of Write Time | $t_{DH}$ | 0 | - | 0 | - | 0 | - | ns |
| Output Active from End of Write | $t_{OW}$* | 4 | - | 5 | - | 6 | - | ns |
| Write to Output in High-Z | $t_{WHZ}$* | - | 8 | - | 9 | - | 10 | ns |

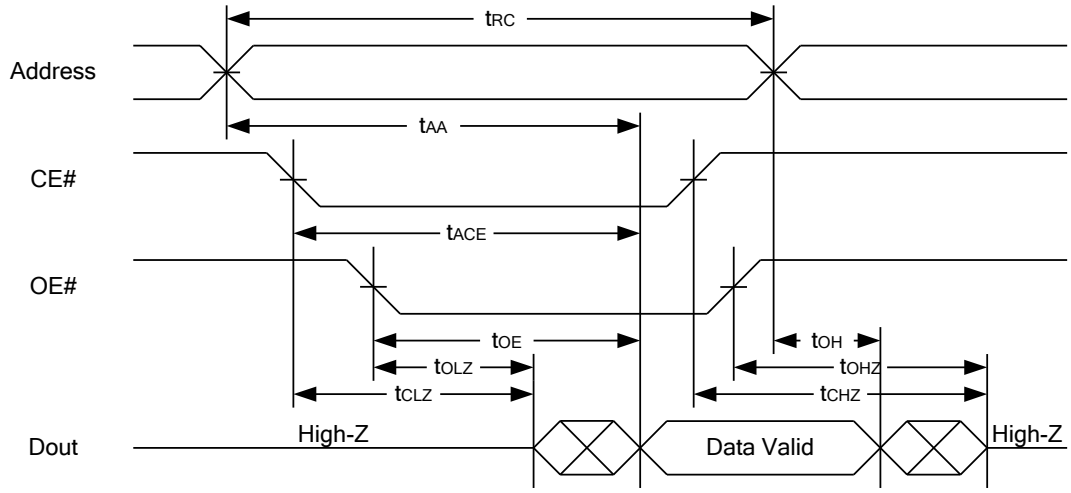
*These parameters are guaranteed by device characterization, but not production tested.

## TIMING WAVEFORMS

**READ CYCLE 1** (Address Controlled) (1,2)

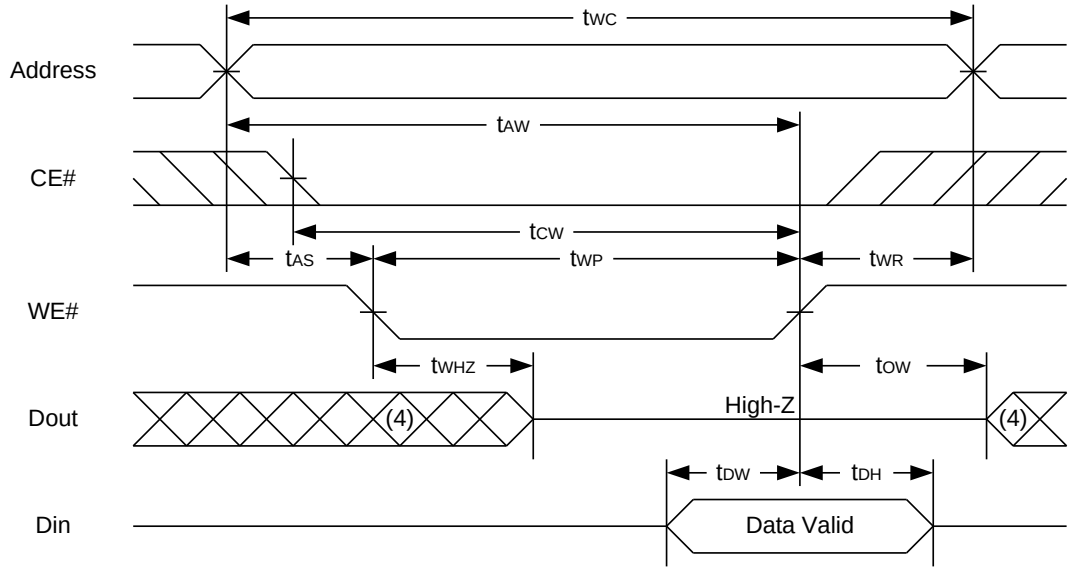



**READ CYCLE 2** (CE# and OE# Controlled) (1,3,4,5)

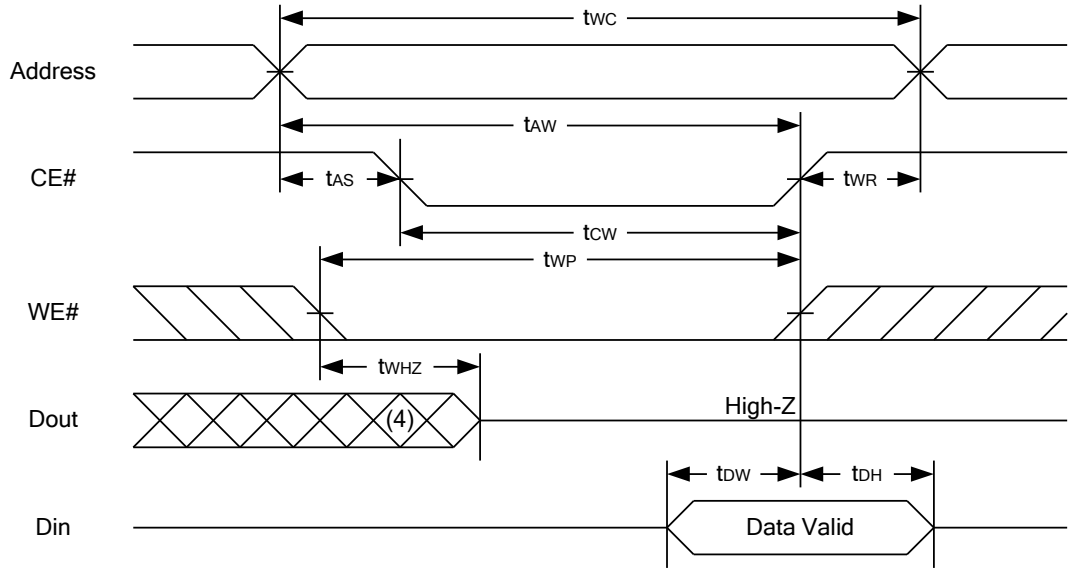



Notes :
1.WE# is high for read cycle.
2.Device is continuously selected OE# = low, CE# = low.
3.Address must be valid prior to or coincident with CE# = low; otherwise $t_{AA}$ is the limiting parameter.
4.$t_{CLZ}$, $t_{OLZ}$, $t_{CHZ}$ and $t_{OHZ}$ are specified with $C_L$ = 5pF. Transition is measured ±500mV from steady state.
5.At any given temperature and voltage condition, $t_{CHZ}$ is less than $t_{CLZ}$ , $t_{OHZ}$ is less than $t_{OLZ}$.

**WRITE CYCLE 1** (WE# Controlled) (1,2,4,5)




**WRITE CYCLE 2** (CE# Controlled) (1,4,5)



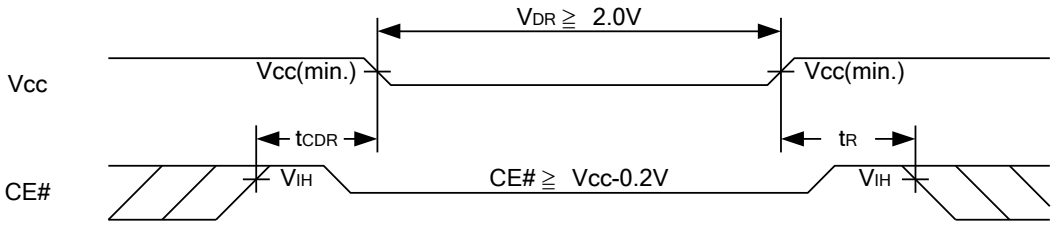

Notes :
1.A write occurs during the overlap of a low CE#, low WE#.
2.During a WE# controlled write cycle with OE# low, $t_{WP}$ must be greater than $t_{WHZ} + t_{DW}$ to allow the drivers to turn off and data to be placed on the bus.
3.During this period, I/O pins are in the output state, and input signals must not be applied.
4.If the CE# low transition occurs simultaneously with or after WE# low transition, the outputs remain in a high impedance state.
5.$t_{OW}$ and $t_{WHZ}$ are specified with $C_L$ = 5pF. Transition is measured ±500mV from steady state.

## DATA RETENTION CHARACTERISTICS

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|---|---|---|---|---|---|---|
| $V_{CC}$ for Data Retention | $V_{DR}$ | CE# ≧ $V_{CC}$ - 0.2V | 2.0 | - | 5.5 | V |
| Data Retention Current | $I_{DR}$ | $V_{CC}$ = 2.0V , CE# ≧ $V_{CC}$ - 0.2V<br>Others at 0.2V or $V_{CC}$-0.2V | - | 0.05 | 2 | mA |
| Chip Disable to Data Retention Time | $t_{CDR}$ | See Data Retention Waveforms (below) | 0 | - | - | ns |
| Recovery Time | $t_R$ | | $t_{RC*}$ | - | - | ns |

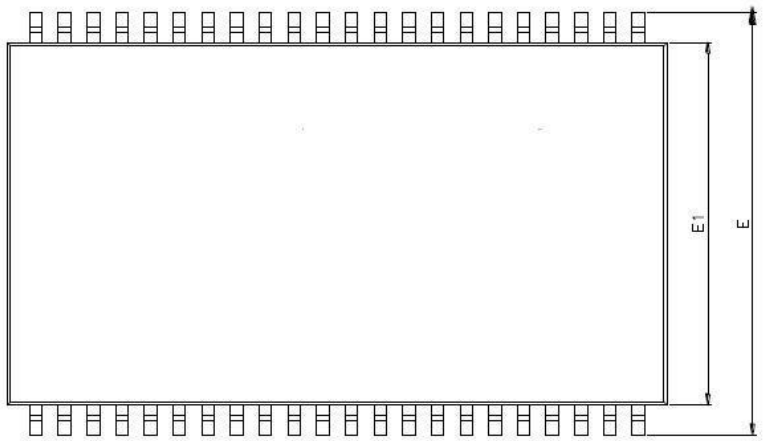
$t_{RC*}$ = Read Cycle Time

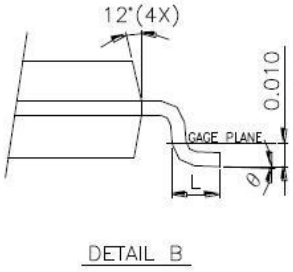
## DATA RETENTION WAVEFORM

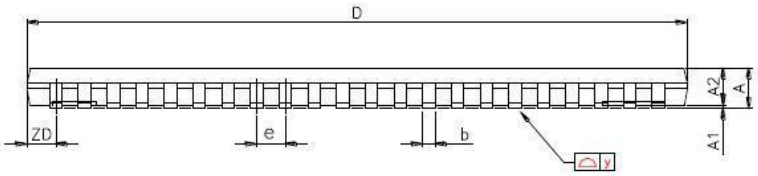


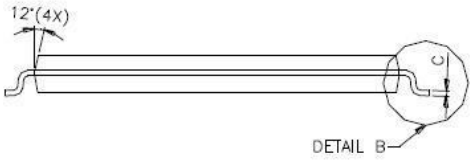
## PACKAGE OUTLINE DIMENSION

### 44-pin 400 mil TSOP Ⅱ Package Outline Dimension




| SYMBOLS | DIMENSIONS IN MILLMETERS | | | DIMENSIONS IN MILS | | |
|---|---|---|---|---|---|---|
| | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. |
| A | - | - | 1.20 | - | - | 47.2 |
| A1 | 0.05 | 0.10 | 0.15 | 2.0 | 3.9 | 5.9 |
| A2 | 0.95 | 1.00 | 1.05 | 37.4 | 39.4 | 41.3 |
| b | 0.30 | - | 0.45 | 11.8 | - | 17.7 |
| c | 0.12 | - | 0.21 | 4.7 | - | 8.3 |
| D | 18.212 | 18.415 | 18.618 | 717 | 725 | 733 |
| E | 11.506 | 11.760 | 12.014 | 453 | 463 | 473 |
| E1 | 9.957 | 10.160 | 10.363 | 392 | 400 | 408 |
| e | - | 0.800 | - | - | 31.5 | - |
| L | 0.40 | 0.50 | 0.60 | 15.7 | 19.7 | 23.6 |
| ZD | - | 0.805 | - | - | 31.7 | - |
| y | - | - | 0.076 | - | - | 3 |
| θ | 0° | 3° | 6° | 0° | 3° | 6° |

## ORDERING INFORMATION

| Package Type | Access Time (Speed)(ns) | Temperature Range(℃) | Packing Type | Lyontek Item No. |
|---|---|---|---|---|
| 44-pin (400mil) TSOP II | 15 | 0℃~70℃ | Tray | LY612568ML-15 |
| | | | Tape Reel | LY612568ML-15T |
| | | -20℃~80℃ | Tray | LY612568ML-15E |
| | | | Tape Reel | LY612568ML-15ET |
| | | -40℃~85℃ | Tray | LY612568ML-15I |
| | | | Tape Reel | LY612568ML-15IT |
| | 20 | 0℃~70℃ | Tray | LY612568ML-20 |
| | | | Tape Reel | LY612568ML-20T |
| | | -20℃~80℃ | Tray | LY612568ML-20E |
| | | | Tape Reel | LY612568ML-20ET |
| | | -40℃~85℃ | Tray | LY612568ML-20I |
| | | | Tape Reel | LY612568ML-20IT |
| | 25 | 0℃~70℃ | Tray | LY612568ML-25 |
| | | | Tape Reel | LY612568ML-25T |
| | | -20℃~80℃ | Tray | LY612568ML-25E |
| | | | Tape Reel | LY612568ML-25ET |
| | | -40℃~85℃ | Tray | LY612568ML-25I |
| | | | Tape Reel | LY612568ML-25IT |

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